



JST08C-800C 8A TRIAC

Rev.A.1.1

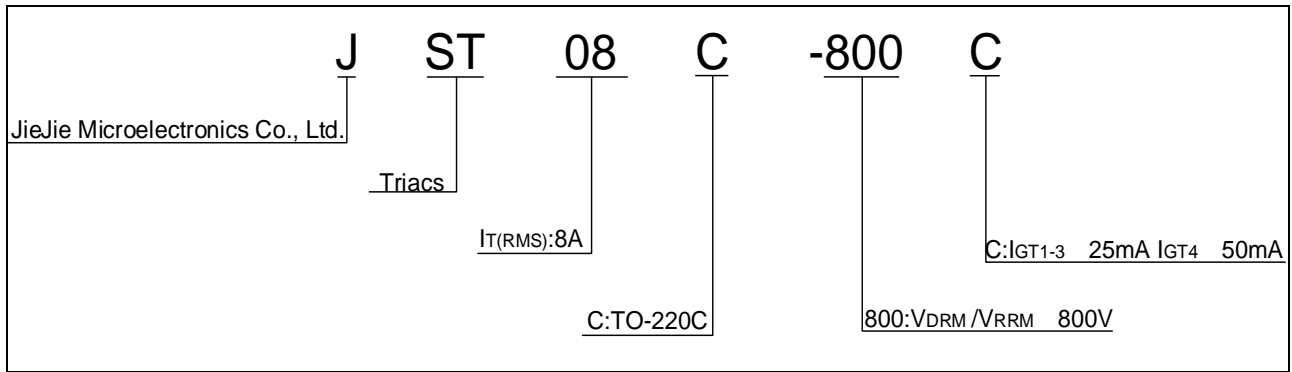
DESCRIPTION:

The JST08C-880

ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33$	- -	MAX.	25	mA
				50	
V_{GT}		ALL	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k$	ALL	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	- -	MAX.	40	mA
				80	
I_H	$I_T=200mA$		MAX.	30	mA
dV/dt	$V_D=540V$ Gate Open $T_j=125$		MIN.	500	V/ μs
$(dV/dt)_c$	$(dI/dt)_c=3.5A/ms$, $T_j=125$		MIN.	6	V/ μs
t_{on}	$I_G=80mA$ $I_A=400mA$ $I_R=40mA$ $T_j=25$		TYP.	5	μs
t_{off}				30	

ORDERING INFORMATION



MARKING

FIG.1: Maximum power dissipation versus RMS on-state current

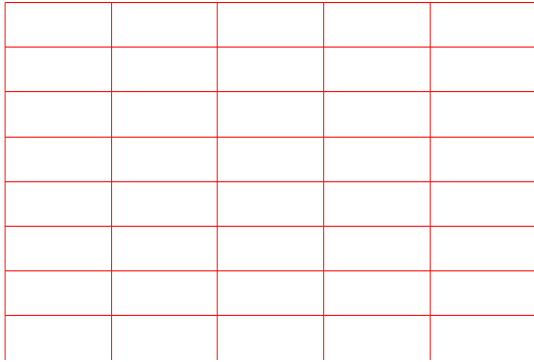



FIG.2: RMS on-state current versus case temperature

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